
FORM PTO-1449 (Modified)		Atı	torney Docket No.: A503	Application No.: Unassigned							
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary)		Ap	Applicant: SCOTT BRAD HERNER								
		Fil	ling Date: Herewith		Group: Unassigned						
Reference Desig	nation		U.S. 1	PATENT DOCUMENT		<u></u>	Page 1				
Examiner Initial	Document No.	Date		Name	Class	Sub-class	Filing Date (If Appropriate)				
TN AA	5,306,666	04/26/94	Izu	ımi	437	192	П'Арргориас				
AB	5,328,722	07/12/94	+	nanayem, et al.	427	250					
AC	5,429,991	07/04/95	+	vasaki, et al.	437	192					
AD	5,599,639	02/04/97	+	nsone, et al.	429	33					
AE AE	6,303,480 B1	10/16/01	 	esai, et al.	438	584					
AF											
AG						· · ·					
AH											
AI											
AJ											
		FOF	ŒIG	ON PATENT DOCUME	ENTS						
	Document No. Date			Country	Class	Sub-class	Translation (Yes/No)				
AK											
AL											
				g Author, Title, Date, Po							
AM AM											
TO AN	MCINERNEY, E.J., et al., "Silane Reduced Chemical Vapor Deposition Tungsten as a Nucleating Step in Blanket W," J. Vac. Sci. Technol. B 11 (3), May/Jun 1993, pp. 734-743.										
IN AO	RAMANATH, G., et al., "Gas-Phase Transport of WF ₆ through Annular Nanopipes in TiN During Chemical Vapor Deposition of W on TiN/Ti/SiO ₂ Structures for Integrated Circuit Fabrication," Appl. Phys. Lett. 69 (21), 18 November 1996, pp. 3179-3181.										
TW AP	NANDA, Arun K., et al., "Characterization of the Nucleation and Growth Process of CVD-W on TiN Substrates," Mat. Res. Soc. Symp. Proc. Vol. 382, 1995 Materials Research Society, pp. 401-406.										
TNAQ											
AR					,						
AS											
EXAMINER	Thur		$\overline{\mathbf{D}}$	DATE CONSIDERED	1/9/07						

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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